## NSN 5962-01-110-6892



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-110-6892 **Overall Height:** 0.365 inches **Body Length:** 0.810 inches **Body Width:** Between 0.270 inches and 0.305 inches **Body Height:** Between 0.105 inches and 0.145 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and 3-state output and low power and w/enable and monolithic **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 18.3 volts power source **Time Rating Per Chacteristic:** 1200.00 nanoseconds propagation delay time, low to high level output and 1200.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Memory Capacity:** Unknown **Terminal Type And Quantity:** 16 printed circuit Shelf Life:

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

N/a

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